200µA to 2000µA

4.90mm x 6.00mm x 1.65mm



# **LIN Transceiver for Automotive**

# BD41030FJ-C BD41030HFN-C

#### **General Description**

BD41030FJ-C,BD41030HFN-C is the best transceiver for BUS system which need LIN (Local Interconnect Network) master and slave protocol.

BD41030FJ-C,BD41030HFN-C is low standby electricity consumption in sleep mode.

BD41030FJ-C:SOP-J8

BD41030HFN-C:HSON8

#### **Features**

- Compliant with LIN2.0,LIN2.1,LIN2.2,LIN2.2A
- AEC-Q100 Qualified<sup>(Note 1)</sup>
- Absolute maximum ratings of LIN pin is -27V to+40V
- Max transmission rate 20kbps
- Low Electro Magnetic Emission (EME)
- High Electro Magnetic Immunity (EMI)
- High impedance at power off for bus
- Interface (RXD/TXD) with protocol layer corresponds to 3.3V/5.0V logic.
- Built-in terminator for LIN slave
- Standby power consumption in sleep mode
- Transmit data(TXD) dominant time-out function
- Resistant to LIN-BAT/GND short-circuit
- Built-in Thermal Shut Down(TSD)

(Note1:Grade1)

### **Applications**

LIN communication for Automotive networks.

### **Key Specifications**

Supply Voltage: 5V to 27V
 Supply Current (Sleep mode): 1µA to 8µA
 Supply Current: 100µA to 1000µA

(Standby mode; Recessive)

Supply Current: 100μA to 1000μA (Normal mode; Recessive)

Supply Current: (Normal mode; Dominant)

Package(s) W(Typ) x D(Typ) x H(Max)

■SOP-J8



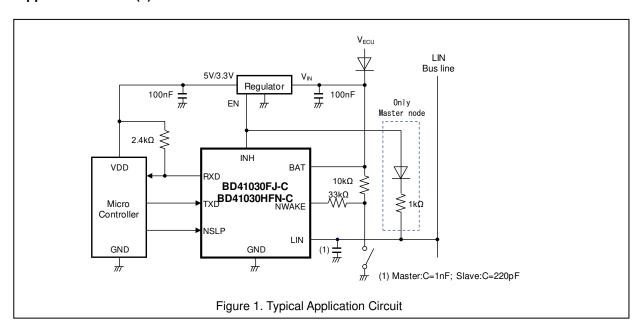
SOP-J8(BD41030FJ-C)

■HSON8 2.90mm x 3.00mm x 0.60mm



HSON8(BD41030HFN-C)

### Typical Application Circuit(s)



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# Pin Configuration(s)

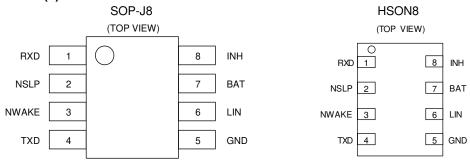


Figure 2. Pin Configuration

# Pin Description(s)

Table 1. Pin Description

| Pin No. | Pin Name | Function  |
|---------|----------|---|
| 1       | RXD      | Received data output pin (Open Drain). "L" is output at standby mode.                       |
| 2       | NSLP     | Sleep control input pin ("L" Active mode). Shift to sleep mode by "L" input in normal mode. |
| 3       | NWAKE    | Local wake-up input pin ("L" Active mode). Active at leading edge.                          |
| 4       | TXD      | Transmission data input pin   |
| 5       | GND      | Ground  |
| 6       | LIN      | LIN bus input and output pin.   |
| 7       | BAT      | Power supply pin.   |
| 8       | INH      | Sleep status indicator. "Hi-z" at sleep mode and "H" in the other modes.                    |

# **Block Diagram(s)**

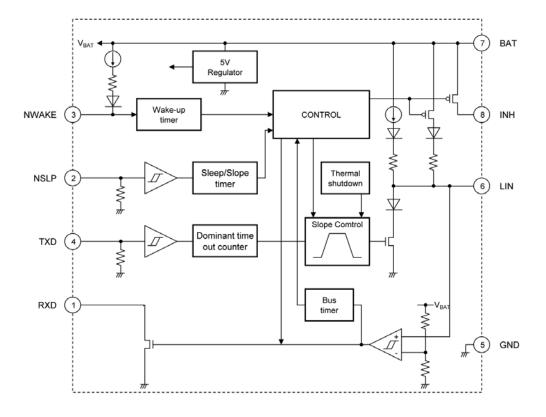


Figure 3. Block diagram

### Description of Block(s)

#### 1. Sleep mode

In sleep mode, the transmit/receive function is not available and BD41030FJ-C is under the condition of low power consumption mode. In this mode BD41030FJ-C shifts to sleep mode at startup of power supply (V<sub>BAT</sub>) when NSLP is "L' or in normal mode also when pin NSLP is "L".

During sleep mode, one of the following wake-up events triggers a shift of state:

- Pin NWAKE "H" → "L" (Shift to standby mode)
- Pin LIN "H" → "L" → "H" (Shift to standby mode)
- Pin NSLP "L"  $\rightarrow$  "H" (Shift to normal mode)

The above-mentioned wake-up events shift the mode when a state remains for a given period of time (tnwake, tbus, taotonorm). Hereinafter, a wake-up event on pin NWAKE is defined as Local wake-up, and a wake-up event on pin LIN is defined as Remote wake-up.

#### 2. Standby mode

When a wake-up event occurs on pin NWAKE or pin LIN in sleep mode, BD41030FJ-C shifts to standby mode. In standby mode, pins become the following state:

- Pin INH "H" (≒V<sub>BAT</sub> voltage)
  Pin RXD "L" (Informs the microcontroller of being in standby mode.)
- · Pin LIN Slave resistor ON

BD41030FJ-C shifts from standby mode to normal mode when pin NSLP input switches to "H".

#### 3. Normal mode

BD41030FJ-C shifts to normal mode when pin NSLP switches to "H" in sleep mode or standby mode. In normal mode, data can be transmitted or received through the bus line. When receiving data, the transceiver informs a LIN bus input from pin RXD to the microcontroller. When transmitting data, the transceiver converts a TXD input signal to a slew-rate-controlled LIN bus signal and informs the bus line of the converted signal. The maximum operating frequency in this mode is 10 kHz.

From this mode, BD41030FJ-C shifts to sleep mode when pin NSLP input switches to "L" and this state remains for a given period of time (tgotosleep).

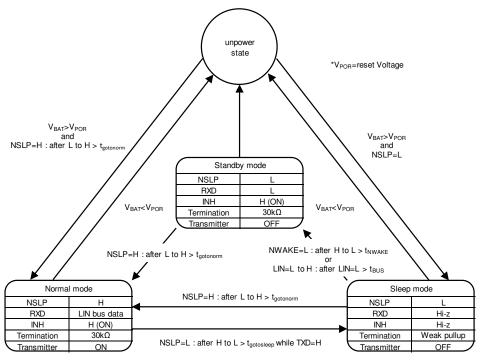


Figure 4. State Transition Chart

Table 2 The state of the pin in each mode

| MODE         | NSLP | TXD       | RXD                                    | INH  | TRANSMITTER |
|--------------|------|-----------|--|------|-------------|
| Sleep mode   | L    | pull-down | Hi-z                                   | Hi-z | OFF         |
| Standby mode | L    | pull-down | L                                      | Н    | OFF         |
| Normal mode  | Н    | pull-down | H : recessive state L : dominant state | Н    | ON          |

#### 4. TXD dominant time-out counters Fail-safe function

A TXD dominant time-out counter prevents the bus line from being driven to a permanent dominant state (blocking all network communication) in case pin TXD input is forced permanently low by a hardware and/or software application failure. The timer is trigged by a negative edge on pin TXD and in case the value exceeds the internal timer value (tdom), the transmitter becomes disabled and drives the bus line into a recessive state. The timer is reset by a positive edge on pin TXD input.

### 5. Fail-safe function

- Pin TXD provides a pull-down to GND in order to force a predefined level on input pin TXD in case the pin TXD is not connected.
- Pin NSLP provides a pull-down to GND in order to force the transceiver into sleep mode in case the pin NSLP is not connected.
- Pin RXD is "Hi-z" in case of lost power supply on pin V<sub>BAT</sub>.
- The output driver at pin LIN will be off when junction temperature exceeds T<sub>J</sub> activating the TSD circuit without relation to input signal at pin TXD. Because the thermal shut down circuitry has a hysteresis band, junction temperature depends on TXD terminal input signal for the LIN terminal output driver again when 15 degrees Celsius (Typ) degree falls from detective temperature.

# Absolute Maximum Ratings (Ta = 25°C)

Table 3. Absolute Maximum Ratings

| Parameter                                      | Symbol                  | Rating                         | Unit |
|--|-------------------------|--------------------------------|------|
| Supply voltage on pin BAT <sup>(Note 1)</sup>  | VBAT                    | -0.3 to +40.0                  | V    |
| DC voltage on pin TXD, RXD, NSLP               | VTXD,<br>VRXD,<br>VNSLP | -0.3 to +7.0                   | V    |
| DC voltage on pin LIN                          | $V_{LIN}$               | -27 to +40                     | V    |
| DC voltage on pin NWAKE                        | VNWAKE                  | -1 to V <sub>BAT</sub> + 0.3   | V    |
| Current on pin NWAKE <sup>(Note 2)</sup>       | INWAKE                  | -15                            | mA   |
| DC voltage on pin INH                          | V <sub>INH</sub>        | -0.3 to V <sub>BAT</sub> + 0.3 | ٧    |
| Output current at pin INH                      | I <sub>INH</sub>        | -50 to +15                     | mA   |
| Power dissipation (SOP-J8) <sup>(Note 3)</sup> | Pd                      | 674                            | mW   |
| Power dissipation (HSON8)(Note 4)              | Pd                      | 630                            | mW   |
| Storage temperature range                      | Tstg                    | -55 to +150                    | °C   |
| Junction Max temperature                       | Tjmax                   | +150                           | °C   |
| Electro static discharge (HBM) (Note 4)        | VESD                    | 4000                           | ٧    |

<sup>(</sup>Note 1) Pd, ASO should not be exceeded.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

# **Recommended Operating Conditions**

Table 4. Recommended Operating Conditions

| Parameter                   | Symbol           | Range       | Unit |
|-----------------------------|------------------|-------------|------|
| Supply voltage              | V <sub>BAT</sub> | 5.0 to 27.0 | V    |
| Operating temperature range | Topr             | -40 to +125 | °C   |

<sup>(</sup>Note 2) Available only when VNWAKE < VGND-0.3V. Current flow to pin GND.

<sup>(</sup>Note 3) Regarding above Ta=25°C, Pd decreased at 5.40mW/°C for temperatures when mounted on 70x70x1.6mm Glass-epoxy PCB.

<sup>(</sup>Note 4) Regarding above Ta=25°C, Pd decreased at 5.04mW/°C for temperatures when mounted on 70x70x1.6mm Glass-epoxy PCB.

<sup>(</sup>Note 5) JEDEC qualified.

Electrical Characteristics (Ta= -40 to +125°C;  $V_{BAT}$  =5 to 27V;  $R_{L(LIN-BAT)}$  =500 $\Omega$ ; typical values are given at Ta=25°C;  $V_{BAT}$  =12V; unless otherwise specified)

Table 5. Electrical Characteristics

|   | lable 5. Electrical Characteristics   |      |      |      |      |   |  |  |
|---|---------------------------------------|------|------|------|------|---|--|--|
| Parameter   | Symbol                                | Min  | Тур  | Max  | Unit | Conditions  |  |  |
| BAT   |                                       |      |      |      |      |   |  |  |
| Supply current 1 on pin BAT (Sleep mode)                      | I <sub>BAT1</sub>                     | 1    | 3    | 8    | μА   | Sleep mode.  VLIN = VBAT  VNWAKE = VBAT  VTXD = 0V  VNSLP = 0V  |  |  |
| Supply current 2 on pin BAT (Standby mode, Recessive)         | I <sub>BAT2</sub>                     | 100  | 400  | 1000 | μА   | Standby mode.  VLIN = VBAT (bus: Recessive)  VINH = VBAT  VNWAKE = VBAT  VTXD = 0V  VNSLP = 0V          |  |  |
| Supply current 3 on pin BAT (Note 1) (Standby mode, Dominant) | Іватз                                 | 300  | 900  | 2000 | μА   | Standby mode.  VBAT = 12V  VLIN = 0V (bus: Dominant)  VINH = VBAT  VNWAKE = VBAT  VTXD = 0V  VNSLP = 0V |  |  |
| Supply current 4 on pin BAT (Normal mode, Recessive)          | I <sub>BAT4</sub>                     | 100  | 400  | 1000 | μА   | Normal mode.  VLIN = VBAT (bus: Recessive)  VINH = VBAT  VNWAKE = VBAT  VTXD = 5V  VNSLP = 5V           |  |  |
| Supply current 5 on pin BAT (Note 1) (Normal mode, Dominant)  | I <sub>BAT5</sub>                     | 200  | 1000 | 2000 | μА   | Normal mode.  VBAT = 12V (bus: Dominant)  VINH = VBAT  VNWAKE = VBAT  VTXD = 0V  VNSLP = 5V             |  |  |
| UVLO threshold voltage  | Vuvlo                                 | -    | -    | 4.9  | V    |   |  |  |
| POR threshold voltage   | V <sub>POR</sub>                      | -    | -    | 4.3  | V    |   |  |  |
| TXD   |                                       |      |      |      | l    |   |  |  |
| High level input voltage                                      | V <sub>IH</sub>                       | 2.0  | -    | 7.0  | V    |   |  |  |
| Low level input voltage                                       | VIL                                   | -0.3 | -    | +0.8 | V    |   |  |  |
| Hysteresis voltage  | V <sub>hys</sub>                      | 0.03 | -    | 0.50 | V    |   |  |  |
| Pull-down resistor  | R <sub>TXD</sub>                      | 125  | 350  | 800  | kΩ   | $V_{TXD} = 5V$  |  |  |
| Low level input current                                       | lıL                                   | -5.0 | 0.0  | +5.0 | μΑ   | $V_{TXD} = 0V$  |  |  |
| NSLP  | · · · · · · · · · · · · · · · · · · · |      |      |      |      |   |  |  |
| High level input voltage                                      | V <sub>IH</sub>                       | 2.0  | -    | 7.0  | V    |   |  |  |
| Low level input voltage                                       | VIL                                   | -0.3 | -    | +0.8 | V    |   |  |  |
| Hysteresis voltage  | V <sub>hys</sub>                      | 0.03 | -    | 0.50 | V    |   |  |  |
| Pull-down resistor  | R <sub>NSLP</sub>                     | 125  | 350  | 800  | kΩ   | V <sub>NSLP</sub> = 5V  |  |  |
| Low level input current                                       | lıL                                   | -5.0 | 0.0  | +5.0 | μA   | V <sub>NSLP</sub> = 0V  |  |  |

(Note 1) When VBAT is 12V or more, add to the circuit current the value calculated by the following expression because IBAT depends on pull-up resistor inside LIN terminal.

$$I_{\rm BAT(increase)} = \frac{V_{\rm BAT} - 12 V}{20 {\rm k}\Omega} \qquad \text{(20k}\Omega \text{ is the minimum value of pull-up resistor inside LIN terminal)}$$

Electrical Characteristics (Ta= -40 to +125°C;  $V_{BAT}$  =5 to 27V;  $R_{L(LIN-BAT)}$  =500 $\Omega$ ; typical values are given at Ta=25°C;  $V_{BAT}$  =12V; unless otherwise specified)

Table 6. Electrical Characteristics

|   | Table 6. E           | electrical (             | Characteri               | stics                       |      |   |
|---|----------------------|--------------------------|--------------------------|-----------------------------|------|---|
| Parameter   | Symbol               | Min                      | Тур                      | Max                         | Unit | Conditions  |
| RXD (open-drain)  |                      |                          |                          |                             |      |   |
| Low level output current  | loL                  | 1.3                      | 3.5                      | -                           | mA   | Normal mode. $V_{\text{LIN}} = 0V$ $V_{\text{RXD}} = 0.4V$  |
| High level leakage current  | Іоzн                 | -5.0                     | 0.0                      | +5.0                        | μΑ   |   |
| NWAKE   |                      |                          |                          |                             |      |   |
| High level input voltage  | ViH                  | V <sub>BAT</sub> - 1.0   | -                        | V <sub>BAT</sub> + 0.3      | V    |   |
| Low level input voltage   | VIL                  | -0.3                     | -                        | V <sub>BAT</sub> - 3.3      | V    |   |
| High level leakage current  | Іін                  | -5.0                     | 0.0                      | +5.0                        | μΑ   | V <sub>NWAKE</sub> = 27V<br>V <sub>BAT</sub> = 27V  |
| Pull-up current   | I <sub>IL</sub>      | -30                      | -10                      | -3                          | μΑ   | V <sub>NWAKE</sub> = 0V   |
| INH   |                      |                          |                          |                             |      | 0   |
| Switch-on resistance between pins BAT and INH                               | RINH                 | -                        | 30                       | 50                          | Ω    | Standby mode, Normal mode.<br>I <sub>INH</sub> = -15mA, V <sub>BAT</sub> = 12V                                  |
| High level leakage current  | lozн                 | -5.0                     | 0.0                      | +5.0                        | μΑ   | Sleep mode.<br>VINH = VBAT = 27V  |
| LIN   | ,                    |                          |                          |                             |      | ,   |
| LIN recessive output voltage  | Vo_rec               | V <sub>BAT</sub> x 0.9   | -                        | $V_{BAT}$                   | V    | $V_{TXD} = 5V$ , $I_{LIN} = 0mA$  |
|   | V <sub>O_dom1</sub>  | -                        | -                        | 1.2                         | V    | $V_{TXD} = 0V$ , $V_{BAT} = 7.3V$   |
| LIN dominant output voltage   | V <sub>O_dom2</sub>  | 0.6                      | -                        | -                           | V    | $\begin{array}{l} V_{TXD} = 0V, \ V_{BAT} = 7.3V \\ R_{L(LIN-BAT)} = 1k\Omega \end{array}$                      |
| Lin dominant output voltage   | Vo_dom3              | -                        | -                        | 2.0                         | V    | $V_{TXD} = 0V$ , $V_{BAT} = 18V$  |
|   | $V_{O\_dom4}$        | 0.8                      | -                        | -                           | V    | $\begin{array}{l} V_{TXD} = 0V, \ V_{BAT} = 18V \\ R_{L(LIN-BAT)} = 1k\Omega \end{array}$                       |
| High level leakage current  | Іін                  | -5.0                     | 0.0                      | +5.0                        | μA   | VLIN = VBAT   |
| LIN pull-up current   | Iι∟                  | -10.0                    | -5.0                     | -2.0                        | μΑ   | Sleep mode.<br>V <sub>LIN</sub> = V <sub>NSLP</sub> = 0V  |
| Pull-up resistance (Slave termination resistance to pin BAT)                | R <sub>SLAVE</sub>   | 20                       | 30                       | 47                          | kΩ   | Standby mode, Normal mode. V <sub>LIN</sub> = 0V, V <sub>BAT</sub> = 12V  |
| Capacitance of pin LIN (Note 2)   | CLIN                 | -                        | -                        | 30                          | pF   |   |
| Short-circuit output current  | I <sub>O_SC0</sub>   | 40                       | -                        | 200                         | mA   | $V_{LIN} = V_{BAT} = 18V, V_{TXD} = 0V$<br>t < t <sub>dom</sub>   |
| Input leakage current at the receiver operating (included pull-up resistor) | IBUS_PAS_dom         | -1                       | -                        | -                           | mA   | $ V_{LIN} = 0V $ $V_{BAT} = 12V $ $V_{TXD} = 5V $   |
| Input leakage current at the receiver operating                             | IBUS_PAS_rec         | -                        | -                        | 20                          | μΑ   | V <sub>LIN</sub> = 18V<br>V <sub>BAT</sub> = 8V<br>V <sub>TXD</sub> = 5V  |
| Loss of ground leakage current  | IBUS_NO_GND          | -1                       | -                        | 1                           | mA   | $V_{BAT} = V_{GND} = 12V$<br>$V_{LIN} = 0V$ to 18V  |
| Loss of battery leakage current   | IBUS_NO_BAT          | -                        | -                        | 100                         | μA   | V <sub>BAT</sub> = 0V<br>V <sub>LIN</sub> = 18V   |
| Receiver threshold voltage  | V <sub>th_rx</sub>   | V <sub>BAT</sub> x 0.4   | -                        | V <sub>BAT</sub> x<br>0.6   | V    | V <sub>BAT</sub> = 7.3V to 27.0V  |
| Receiver center voltage (Note 3)  | V <sub>cn_rx</sub>   | V <sub>BAT</sub> x 0.475 | V <sub>BAT</sub> x 0.500 | V <sub>BAT</sub> x 0.525    | V    | $\begin{array}{c} V_{BAT} = 7.3 V \text{ to } 27.0 V \\ V_{cn\_rx} = (V_{th\_dom} + V_{th\_rec})/2 \end{array}$ |
| Receiver threshold hysteresis voltage (Note 3)                              | $V_{\text{th\_hys}}$ | V <sub>BAT</sub> x 0.100 | V <sub>BAT</sub> x 0.140 | V <sub>ват</sub> х<br>0.175 | V    | $ \begin{array}{c} V_{BAT} = 7.3 V \ to \ 27.0 V \\ V_{th\_hys} = V_{th\_rec} - V_{th\_dom} \end{array} $       |
|   |                      |                          |                          |                             |      |   |

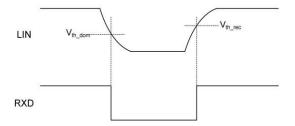
(Note 2) It is a design guarantee parameter, and is not production tested.

Electrical Characteristics (Ta= -40 to +125°C;  $V_{BAT}$  =5 to 27V;  $R_{L(LIN-BAT)}$  =500 $\Omega$ ; typical values are given at Ta=25°C;  $V_{BAT}$  =12V; unless otherwise specified)

Table 7. Electrical Characteristics

|   | Table 7. L             | icotricai c | laracton | 1103  |      | 1   |
|---|------------------------|-------------|----------|-------|------|---|
| Parameter   | Symbol                 | Min         | Тур      | Max   | Unit | Conditions  |
| AC characteristics (Note 7)   |                        | 1           |          |       |      |   |
| RXD propagation delay   | t <sub>PropRxDom</sub> | -           | -        | 6.0   | μs   | Normal mode   |
| had propagation delay   | t <sub>PropRxRec</sub> | -           | -        | 6.0   | μs   | $C_{L(LIN-GND)} = 0nF$<br>$R_{L(LIN-BAT)} = \infty$   |
| RXD propagation delay failure   | ⊿td_(BUS-RXD)          | -2.0        | 0.0      | +2.0  | μs   | Voltage on LIN externally forced. LIN $t_f$ , $t_r < 20$ ns $C_{RXD} = 20$ pF $R_{RXD} = 2.4$ k $\Omega$ $\triangle$ td_(BUS-RXD)= $t_{PropRxDom}$ - $t_{PropRxBec}$  |
| Duty cycle 1 (Note 4, Note 5)   | D1                     | 0.396       | -        | -     |      | Normal mode $TH_{Rec(max)} = 0.744 \text{ x V}_{BAT}$ $TH_{Dom(max)} = 0.581 \text{ x V}_{BAT}$ $V_{BAT} = 7.0 \text{ to } 18.0 \text{ V}$ $t_{Bit} = 50 \mu \text{s}$  |
| Duty cycle 2 (Note 4, Note 6)   | D2                     | -           | -        | 0.581 |      | Normal mode $TH_{Rec(min)} = 0.422 \text{ x V}_{BAT}$ $TH_{Dom(min)} = 0.284 \text{ x V}_{BAT}$ $V_{BAT} = 7.6 \text{ to } 18.0 \text{ V}$ $t_{Bit} = 50 \mu \text{s}$  |
| Duty cycle 3 (Note 4, Note 5)   | D3                     | 0.417       | -        | -     |      | Normal mode<br>TH <sub>Rec(max)</sub> = 0.778 x V <sub>BAT</sub><br>TH <sub>Dom(max)</sub> = 0.616 x V <sub>BAT</sub><br>V <sub>BAT</sub> =7.0 to 18.0V<br>t <sub>Bit</sub> =96µs   |
| Duty cycle 4 (Note 4, Note 6)   | D4                     | -           | -        | 0.590 |      | Normal mode $TH_{\text{Rec}(\text{min})} = 0.389 \text{ x V}_{\text{BAT}}$ $TH_{\text{Dom}(\text{min})} = 0.251 \text{ x V}_{\text{BAT}}$ $V_{\text{BAT}} = 7.6 \text{ to } 18.0 \text{V}$ $t_{\text{Bit}} = 96 \mu \text{s}$ |
| Dominant time for wake-up via bus                                       | tBUS                   | 30          | 70       | 150   | μs   | Sleep mode<br>(Remote wake-up)  |
| Dominant time for wake-up via pin NWAKE                                 | t <sub>NWAKE</sub>     | 7           | 20       | 50    | μs   | Sleep mode<br>(Local wake-up)   |
| Time period for mode change from sleep or standby mode into normal mode | t <sub>gotonorm</sub>  | 2           | 5        | 10    | μs   | Shift from Sleep/Standby mode to Normal mode  |
| Time period for mode change from normal mode into sleep mode            | t <sub>gotosleep</sub> | 2           | 5        | 10    | μs   | Shift from Normal mode to Sleep mode  |
| TXD dominant time out   | t <sub>dom</sub>       | 6           | 12       | 20    | ms   | $V_{TXD} = 0V$  |
|   |                        |             |          |       |      |   |

(Note 3)



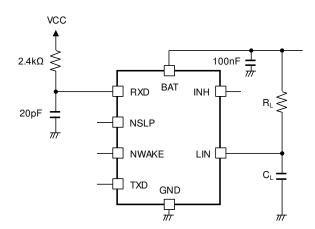
(Note 4) Load condition at bus ( CL(LIN-GND); RL(LIN-BAT) ) : 1nF; 1k $\Omega$  / 6.8nF;  $660\Omega$  / 10nF;  $500\Omega$ 

(Note 5)

$$D1, D3 = \frac{t_{\text{Bus\_rec (min)}}}{2xt_{\text{Bit}}}$$

(Note 6) 
$$D2, D4 = \frac{t_{\mathrm{Bus\_rec\,(max)}}}{2xt_{\mathrm{Bit}}}$$

(Note 7) AC characteristic evaluation circuit diagram



# **Timing Chart**

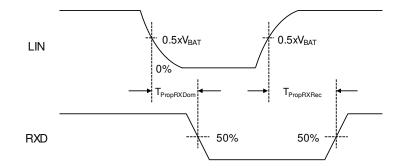


Figure 5. AC characteristic timing chart

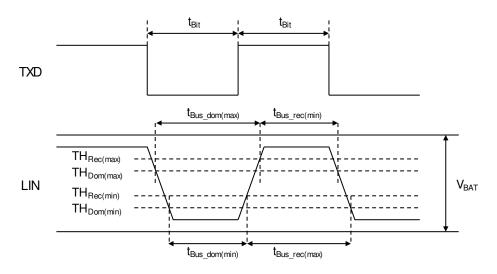


Figure 6. Bus timing chart

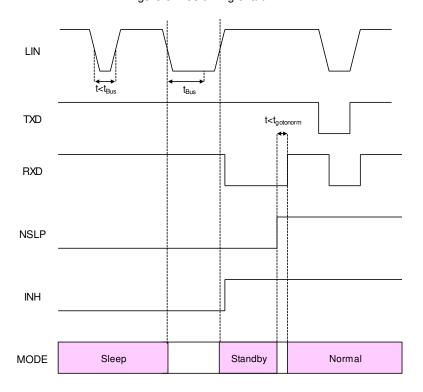


Figure 7. Remote wake-up (Sleep→Standby→Normal)

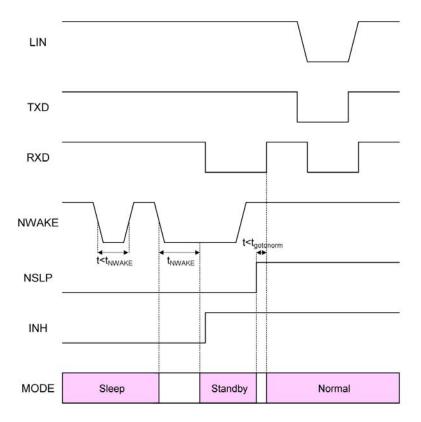


Figure 8. Local wake-up (Sleep→Standby→Normal)

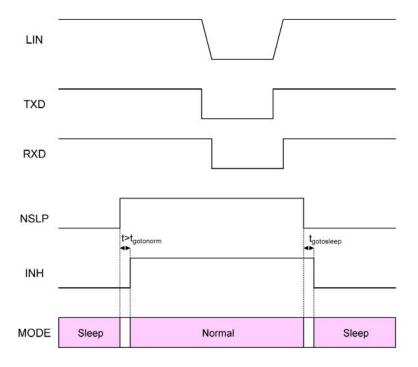


Figure 9. Wake-up/Sleep-in with NSLP (Sleep→Normal→Sleep)

# **Application Example(s)**

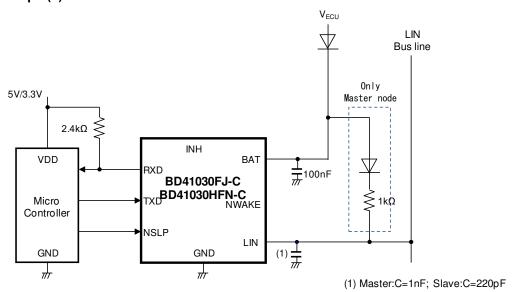
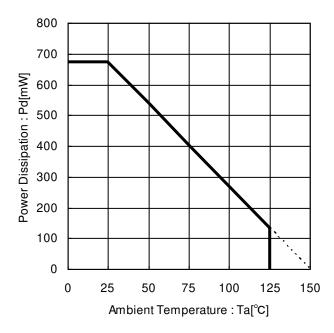


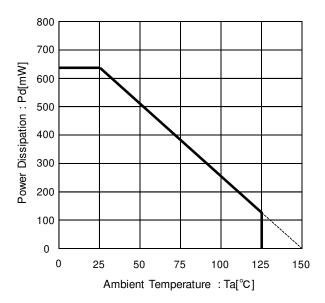
Figure 10. Application Example

# **Power Dissipation**

### ■SOP-J8

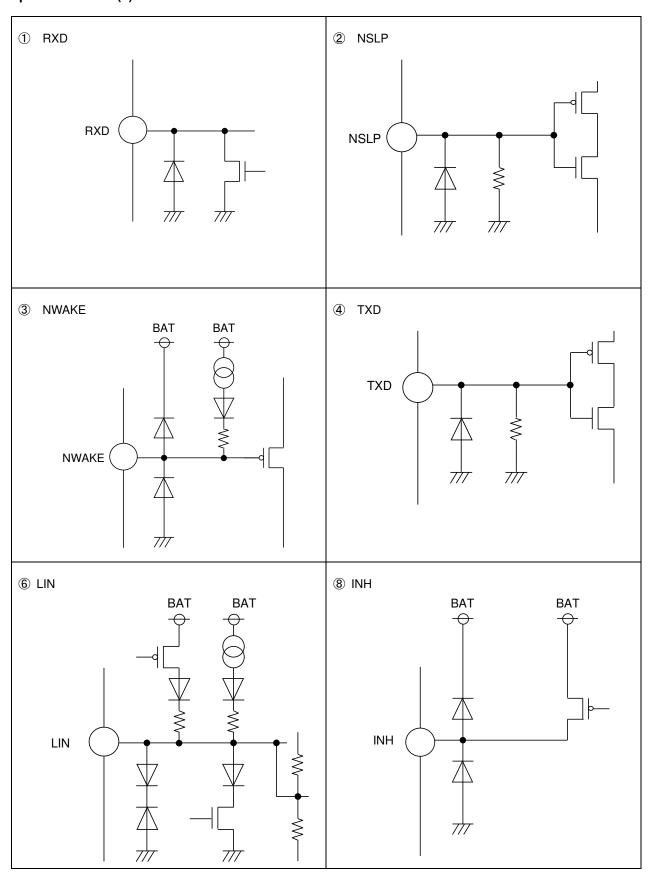


### ■HSON8



(Note 1) Measured Board (70mm x 70mm x 1.6mm, glass epoxy 1-layer) (Note 2) These values are changed by number of layer and copper foil area.

# I/O equivalent circuit(s)



## **Operational Notes**

### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Except for pins the output and the input of which were designed to go below ground, ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

### **Operational Notes - continued**

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

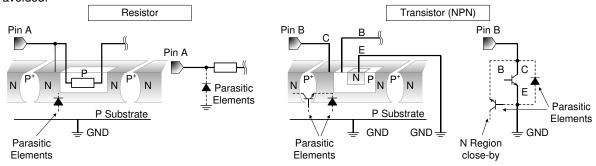


Figure 101. Example of monolithic IC structure

#### 13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### 14. Area of Safe Operation (ASO)

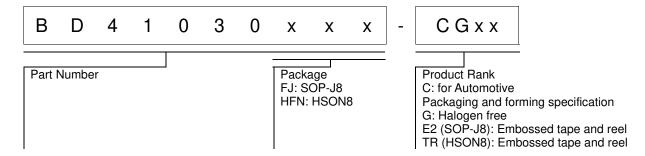
Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

## 15. Thermal Shutdown Circuit(TSD)

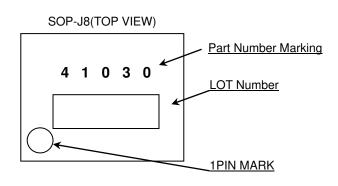
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

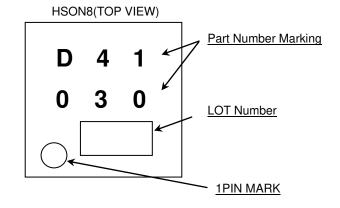
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

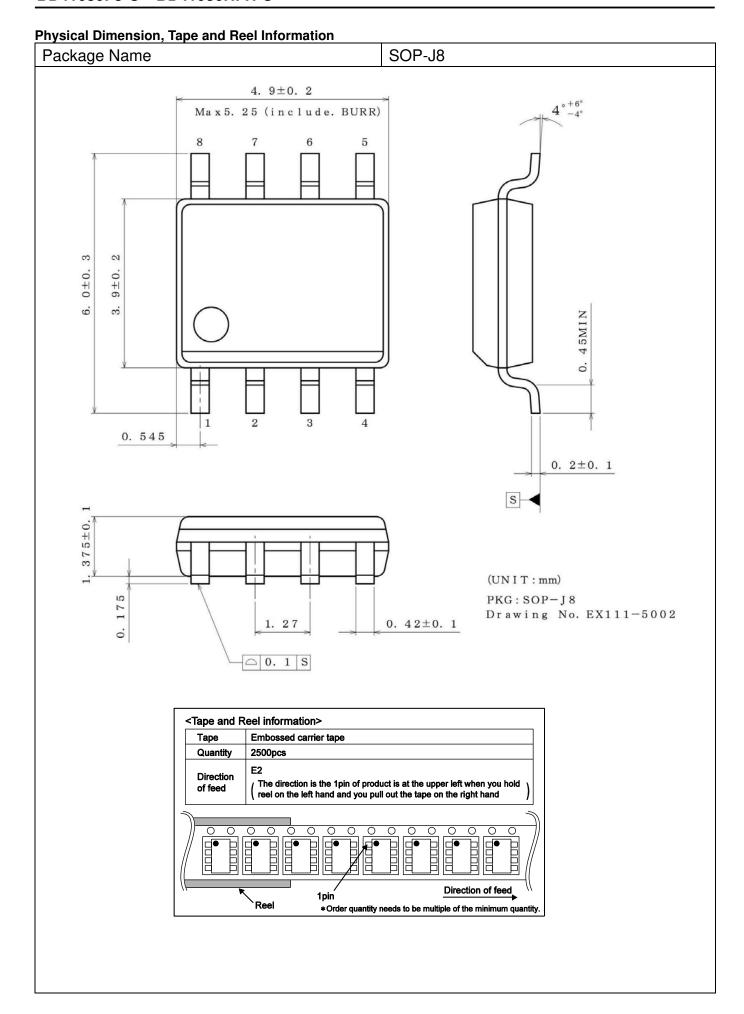
# **Ordering Information**



# **Marking Diagrams**





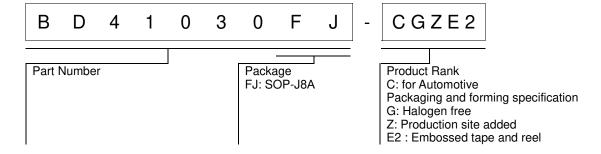


Physical Dimension, Tape and Reel Information HSON8 Package Name (2. 2) $2.9\pm0.1$ (0.05)(MAX3. 1 (include. BURR)) 2 0 3) 7 6 6 15) 0 9 O 45) 0±0  $8\pm0.$ 8 1. 0 3 5) 0.  $13^{+0.1}_{-0.05}$ 0 1PIN MARK 6MAX 0 03 (UNIT: mm) 0 2 + 0. □ 0. 1 S PKG: HSON8 0.65 0. 32±0. 1 ⊕ 0. 08 M Drawing No. EX163-5002 <Tape and Reel information> Tape Embossed carrier tape 3000pcs Quantity TR Direction The direction is the 1pin of product is at the upper right when you hold of feed reel on the left hand and you pull out the tape on the right hand Direction of feed Reel \*Order quantity needs to be multiple of the minimum quantity.

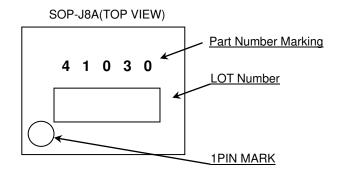
# **Revision History**

| Date        | Revision | Changes  |
|-------------|----------|--|
| 12.Jun.2015 | 001      | New Release  |
| 18.Aug.2016 | 002      | HSON8 Full-scale revision by the package lineup addition     Typical Performance Curves deletion     P1 Modified Typical Application Circuit     P3 Modified Pin Description     P3 Modified Block diagram     P4 Modified State Transition Chart     P5 Modified Fail-safe function     P6 Absolute Maximum Ratings Modified DC voltage on pin NWAKE     P7 Electrical Characteristics Added 「UVLO threshold voltage」「POR threshold voltage」     P8 Electrical Characteristics Modified 「Capacitance of pin LIN」     P13 Modified Application Example     P14 Modified Power Dissipation     P15 Modified I/O equivalent circuit(s) |
| 6.Jan.2021  | 003      | Updated packages and part numbers P.21-2,P21-3   |

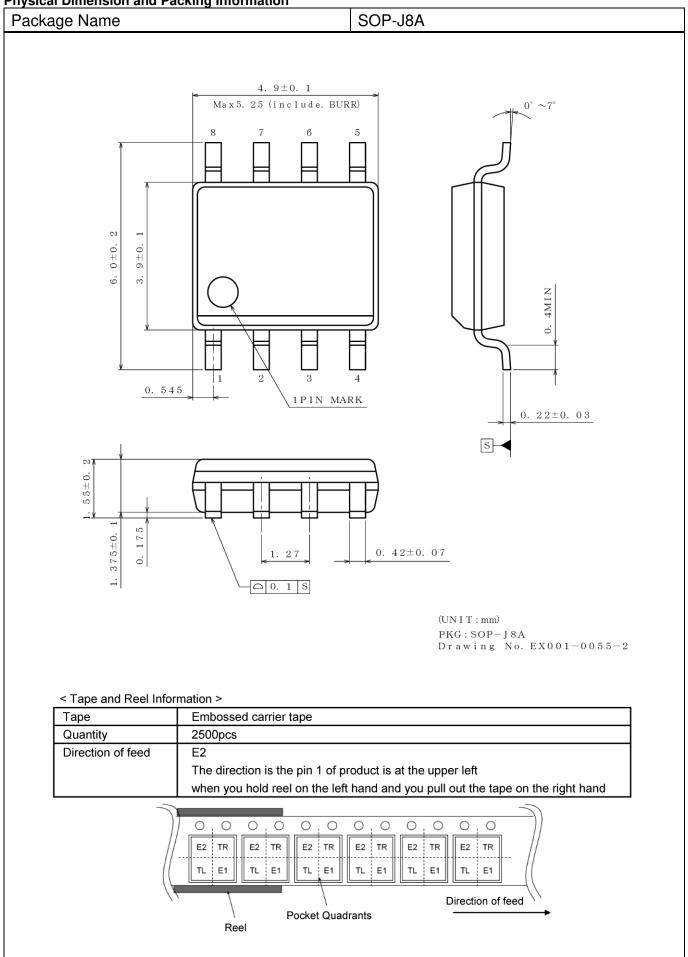
# **Ordering Information**



# **Marking Diagrams**



**Physical Dimension and Packing Information** 



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(Note1) Medical Equipment Classification of the Specific Applications

| 1. toto // modical Equipment elacomodicin el tilo opocino applicatione |          |          |          |  |  |  |  |  |
|--|----------|----------|----------|--|--|--|--|--|
| JAPAN  | USA      | EU       | CHINA    |  |  |  |  |  |
| CLASSⅢ   | CLASSⅢ   | CLASSIIb | CLASSⅢ   |  |  |  |  |  |
| CLASSIV  | CLASSIII | CLASSⅢ   | CLASSIII |  |  |  |  |  |

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  - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
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